

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error	Ref
57	BRS	153	250/492.21 and implant\$6 near5 plasma	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 08:22			S57
58	BRS	11	S57 and irradiat\$4 near5 plasma	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 08:30			S58
59	BRS	0	S57 and irradiat\$4 near5 nitrid\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 08:30			S59
60	BRS	9	S57 and irradiat\$4 and nitrid\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 08:34			S60
61	BRS	2	"4,764,394".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 08:34			S61

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error or Definition	Error or Ref #
62	BRS	12	(US-20050202624-\$ or US-20050136604-\$ or US-20050285208-\$ or US-20050247985-\$ or US-20040107909-\$).did. or (US-6248662-\$ or US-6670224-\$ or US-6909087-\$ or US-6898065-\$ or US-6478924-\$ or US-6180501-\$ or US-6130135-\$).did.	US-PGPUB; USPAT	2006/06/29 09:17			S62
63	BRS	0	S62 and constant near5 DC	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 09:17			S63
64	BRS	4	S62 and constant near5 voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 09:20			S64
65	BRS	11	S62 and nitrid\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 09:21			S65
66	BRS	2	S62 and nitridation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 09:47			S66

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error #	Ref #
67	BRS	31	implant\$6 near5 high adj dielectric adj constant	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 09:49				S67
68	BRS	11	S67 and nitrogen	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 10:50				S68
69	BRS	2	250/492.21 and implantation and kev near5 thickness	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 10:52				S69
70	BRS	395	implantation and kev near5 thickness	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 10:52				S70
71	BRS	91	S70 and "10 kev"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 10:53				S71

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error or Definition	Error #	Ref #
72	BRS	27	S71 and "10 kev" near5 thick\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 10:54				S72
73	BRS	0	S70 and constant near5 DC	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 10:57				S73
74	BRS	23	S70 and constant near5 voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:03				S74
75	BRS	40	S75 and gate adj oxide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:03				S76
76	BRS	10	S76 and oxygen	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:04				S77

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error #	Ref #
77	BRS	131	implant\$6 and constant near5 DC adj voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:06				S75
78	BRS	183	implant\$6 and source near5 DC adj voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:07				S78
79	BRS	8	S78 and constant adj DC	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:07				S79
80	BRS	0	S80 and constant adj DC	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:07				S81
81	BRS	5	S80 and constant adj voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:12				S82

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error	Ref #
82	BRS	20	S80 and constant near5 voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:12			S83
83	BRS	85	ion adj implant\$6 and source near5 DC adj voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:38			S80
84	BRS	164	ion adj implant\$6 and constant near5 voltage adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:39			S84
85	BRS	10	S84 and constant near5 DC	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/29 11:39			S85